

# SEARCHED

Class	Sub.	Date	Exmr.
257	288 327 402 405 410 411	7/13/02	A.M.
438	287 585 591 778 785 786		
A38	216 287 591 785	8/08/03	A.M.
257	324 296 327 411		

## INTERFERENCE SEARCHED

Class	Sub.	Date	Exmr.

## SEARCH NOTES (INCLUDING SEARCH STRATEGY)

	Date	Exmr.
<p>IEEE: MOSFET + Ta<sub>2</sub>O<sub>5</sub> - Oxynitride EAST: US-PUB-EPG JP - Derwent CCLS; MOSFET + High-K or high permittivity - Zirconium and Hafnium and Oxynitride</p>	7/13/02	A.M.
<p>EAST (ALL) x Inventors v x Metal + Silicate + gate dielectric</p>	8/07/03	A.M.